PCN Number:		20130730000						PCN Date:		08/02/2013			
Title: Alternate Assembly Site Qualification													
Customer Contact:		PCN	Mai	<u>nager</u>	Phone	+1(214)	+1(214)480-6037		Dept:	Qua	ality Services		
Propose	d 1 st Ship Da	te:	1	1/02/20	013 E	stimated	Samp	le /	Availabilit	y:	09/02/2013		
Change	Туре:												
Assembly Site			Assembly Process					Assembly Materials					
Desi	gn								Mechanica	Mechanical Specification			
Test	Site			Packing/Shipping/Labeling					Test Process				
Wafe	er Bump Site			Wafer I	Bump Ma	aterial			Wafer Bur	mp P	rocess		
Wafe	er Fab Site			Wafer I	Fab Mate	erials	[Wafer Fab	Pro	cess		
					PCN	Details							
Descript	ion of Chang	je:											
	ion of TI Taiw low. The mat									elect	devices as		
Reason	for Change:												
Continuo	us Customer S	Supp	ly										
Anticipa	ted impact o	n Fo	orm	, Fit, Fu	unction,	Quality of	or Relia	abi	lity (posit	ive /	/ negative):		
None	•					,			,		,		
Changes	to product i	den	tifi	cation r	resulting	g from th	is PCN	:					
Group 1													
Assemb				Λ		ita Oniada	(221)	1	Δ.		Λ.Δ.Δ.		
	TI Malaysia				Assembly Site Origin (22L) Assembly Site Origin (22L)					<u>SO: </u>			
TI Taiwan				ASS	serribly 3	ite Origin	(ZZL)		A	30.	IAI		
Group 2													
Assemb							/·\						
						ite Origin		-	ASO: QAB				
TI Malaysia Assembly Site Origin (22L) ASO: MLA						MLA							
MADE IN: 2DC: MSL 1 /2 OPT: ITEM:	AS MENTS MALAYSIA 20: 60C/1 YEAR SEAL 35C/UNLIM 03/2	DT 9/04	bel	(not a		1P) \$N74 (Q) 2000 31T) LOT: 4W) TKY (P) 2P) REV: 20L) CSO: SI 22L) ASO: M	LSO7NS (D 39590 1T) 752) () 147N 234					

Topside Device marking: Assembly site code for TI Clark = I Assembly site code for TI Malaysia = K Assembly site code for TI Taiwan = T

Product Affected:								
Group 1: Adding TI Taiwan								
HPA00694DBTR	HPA00954DBTR	TPD12S521DBTR/2354	TPD12S521DBTRG4					
HPA00885DBTR	TPD12S521DBTR							
Group 2: Adding TI Malaysia								
TXS02326AMRGER								

TI Taiwan Qualification Data: Approved July 2013									
This qualification has been specifically developed for the validation of this change. The qualification data									
validates that the proposed chan	validates that the proposed change meets the applicable released technical specifications.								
Qualification Device: TPD12S521DBTR (MSL2-260C)									
Package Construction Details									
Assembly Site:	TAI	Mold Compound:	4206193						
# Pins-Designator, Family:	38-DBT, TSSOP	Mount Compound:	4042500						
Lead Finish:	NiPdAu, Cu	0.96 Mil Dia., Cu							
Qualification: Plan	Qualification: Plan Test Results								
Reliability Test	Conditions	Sample Size / Fail							
Electrical Characterization	Per PDS range	Pass							
X-ray	(top side only)	Pass							

TI Taiwan Refere	ence	Qualification	n Data: Approv	ed	Janı	uary 20	008	
This qualification has been sp validates that the proposed cl		J 1		0			tion data	
Qualit	ficat	ion Device: BQ	8015DBT (MSL 2-2	260	c)			
Package Construction Details								
Assembly Site:	TAI		Mold Compou	nd:	4206	5193		
# Pins-Designator, Family:	38-[OBT, TSSOP	Mount Compou	nd:	4042	4042500		
Leadframe (Finish, Base):	NiPo	lAu, Cu	Bond W	0.96 Mil Dia., Cu				
Qualification: Plan Test Results								
Reliability Test		Conditions			Sam	ple Size / Fail		
				Lo	ot 1	Lot 2	Lot 3	
**High Temp Operating Lif	fe	155C (240 Hrs))	4	0/0	40/0	40/0	
**High Temp. Storage Bak	кe	170C (420 Hrs)	(420 Hrs)		7/0	77/0	77/0	
**Biased HAST		130C/85%RH (96 Hrs)			0/0	40/0	40/0	
**Autoclave 121C		121C, 2 ATM (96 Hrs)			7/0	77/0	77/0	
**T/C -65C/150C		-65C/+150C (500 Cyc)			7/0	77/0	77/0	
**Thermal Shock	·	-65C/+150C (500 Cyc)			7/0	77/0	77/0	
Notes: **Tests received pr	recon	ditioning seque	nce: MSL2-260C			•		

TI Malaysia Qualification Data: Approved July 2013								
This qualification has been specifically developed for the validation of this change. The qualification data								
validates that the proposed chan	validates that the proposed change meets the applicable released technical specifications.							
Qualification Device: TXS02326AMRGER (MSL2-260C)								
Package Construction Details								
Assembly Site:	MLA	Mold Compound:	4208625					
# Pins-Designator, Family:	24-RGE, VQFN	Mount Compound:	4205846					
Lead Finish:	NiPdAu, Cu Bond Wire:		0.96 Mil Dia., Cu					
Qualification: Plan	Test Results							
Reliability Test	Conditions	Sample Size / Fail						
Electrical Characterization	Per PDS range	Per PDS range						
X-ray	(top side only)	Pass						

TI Malaysia Reference Qualification Data: Approved March 2007								
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.								
Qualification Device: TSC2200RHB (MSL 2-260c)								
Package Construction Details								
Assembly Site: MLA Mold Compound: 4208625								
# Pins-Designator, Family: 24-F		RGE, VQFN	Mount Compound		nd:	4205846		
Leadframe (Finish, Base):	NiPo	dAu, Cu Bond Wir		re:	0.96 Mil Dia., Cu			
Qualification: Plan Test Results								
Reliability Test			Sample Size / Fa		′ Fail			
Reliability Test		Conditions		Lo	ot 1	Lot 2	Lot 3	
**Steady-state Life Test		150C (168, 300 Hrs)			116/0		116/0	116/0
**High Temp. Storage Bake		150C (1000 Hrs)		77/0		77/0	77/0	
**Biased HAST		130C/85%RH (96 Hrs)		40/0		40/0	40/0	
**Autoclave 121C		121C, 2 ATM (96 Hrs)		77/0		77/0	77/0	
**T/C -65C/150C	-65C/+150C (500 Cyc)			77/0		77/0	77/0	
Notes: **Tests received preconditioning sequence: MSL2-260C								

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com